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Low V_{CE(sat)} NPN Transistor 60 V, 2 A

NSS60201SMT

onsemi's e²PowerEdge family of low $V_{CE(sat)}$ transistors are miniature surface mount devices featuring ultra low saturation voltage $(V_{CE(sat)})$ and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and LED lightning, power management...etc. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- NSV60201SMTWTBG Wettable Flanks Device
- These Devices are Pb-Free, Halogen Free / BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Мах	Unit
Collector-Emitter Voltage	V _{CEO}	60	Vdc
Collector-Base Voltage	V _{CBO}	60	Vdc
Emitter-Base Voltage	V _{EBO}	6	Vdc
Collector Current – Continuous	Ι _C	2	А
Collector Current – Peak	I _{CM}	3	А

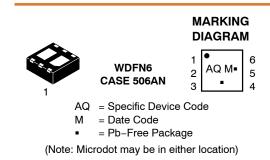
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

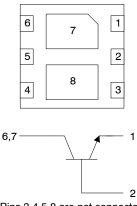
Characteristic	Symbol	Мах	Unit
Thermal Resistance Junction-to-Ambient (Note 2)	$R_{\theta JA}$	69	°C/W
Total Power Dissipation @ $T_A = 25^{\circ}C$ (Note 2)	PD	1.8	W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

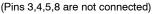
2. Per JESD51-7 with 100 mm² pad area and 2 oz. Cu.

60 Volt, 2 Amp NPN Low V_{CE(sat)} Transistor



PIN CONNECTIONS





ORDERING INFORMATION

Device	Package	Shipping [†]
NSS60201SMTTBG	WDFN6 (Pb-Free)	3000 / Tape & Reel

DISCONTINUED (Note 1)

NSV60201SMTWTBG	WDFN6	3000 /
	(Pb-Free)	Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

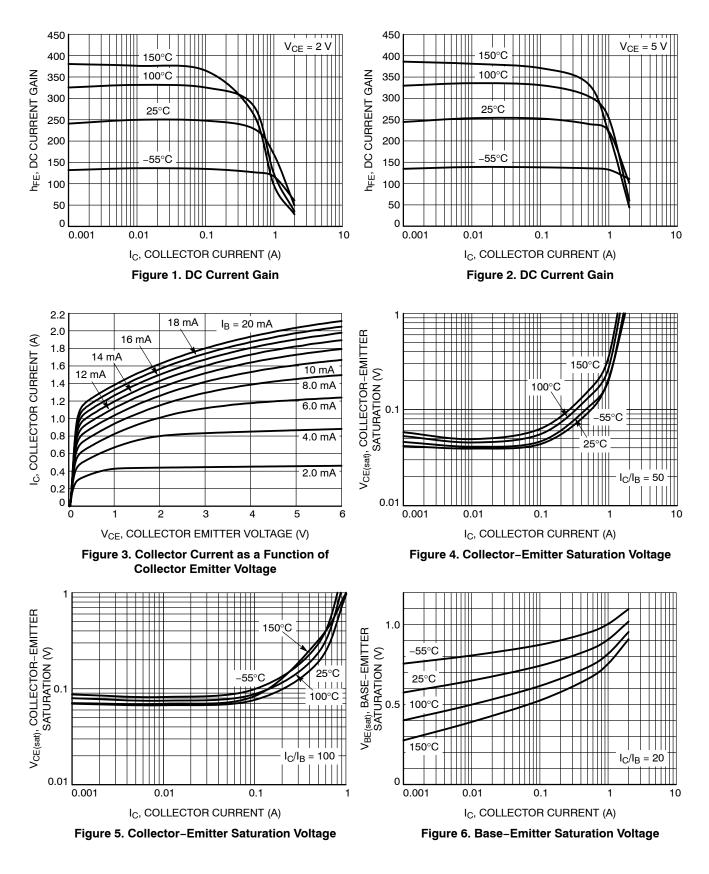
1. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on <u>www.onsemi.com</u>.

Table 1. ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

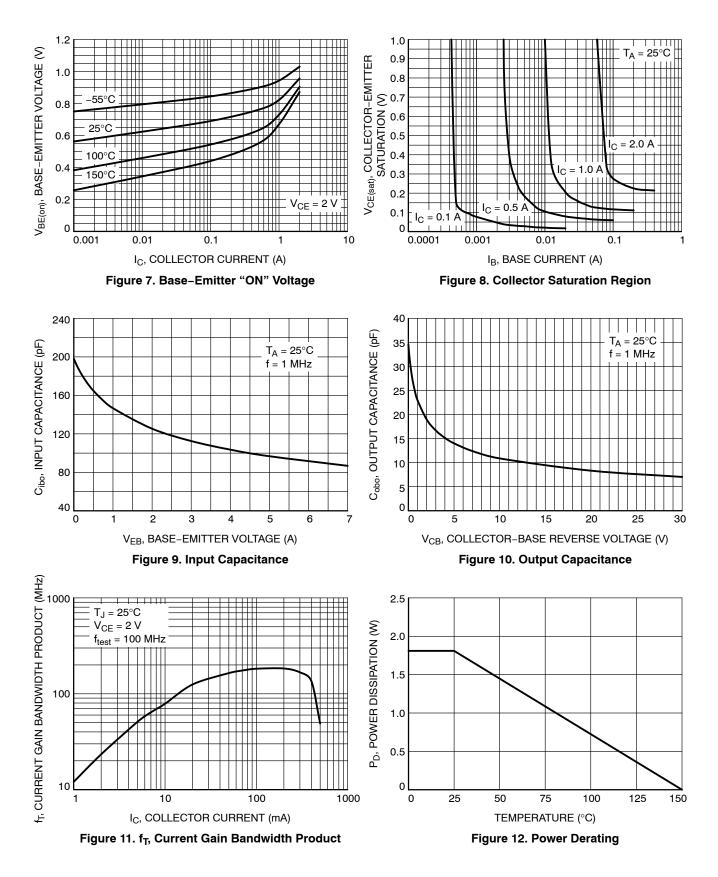
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ($I_C = 10 \text{ mA}, I_B = 0$)	V _{(BR)CEO}	60	-	-	V
Collector-Base Breakdown Voltage (Ic = 0.1 mA, $I_E = 0$)	V _{(BR)CBO}	80	-	-	V
Emitter-Base Breakdown Voltage ($I_E = 0.1 \text{ mA}, I_C = 0$)	V _{(BR)EBO}	6	-	-	V
Collector Cutoff Current (V _{CB} = 60 V, I_E = 0)	I _{CBO}	-	-	100	nA
Emitter Cutoff Current (V _{BE} = 5.0 V)	I _{EBO}	_	-	100	nA
ON CHARACTERISTICS					
DC Current Gain (Note 3) ($I_C = 100 \text{ mA}, V_{CE} = 2.0 \text{ V}$) ($I_C = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}$) ($I_C = 1 \text{ A}, V_{CE} = 2.0 \text{ V}$) ($I_C = 2 \text{ A}, V_{CE} = 2.0 \text{ V}$	h _{FE}	150 120 90 35	250 240 180 55	- - - -	-
Collector-Emitter Saturation Voltage (Note 3) ($I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$) ($I_C = 1 \text{ A}, I_B = 50 \text{ mA}$) ($I_C = 1 \text{ A}, I_B = 100 \text{ mA}$) ($I_C = 2 \text{ A}, I_B = 200 \text{ mA}$)	V _{CE(sat)}	- - -	0.063 0.130 0.115 -	0.100 0.200 0.180 0.250	V
Base – Emitter Saturation Voltage (Note 3) ($I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$) ($I_C = 1 \text{ A}, I_B = 50 \text{ mA}$) ($I_C = 1 \text{ A}, I_B = 100 \text{ mA}$)	V _{BE(sat)}	- - -		1.0 1.0 1.1 1.5	V
Base-Emitter Turn-on Voltage (Note 3) $(I_C = 500 \text{ mA}, V_{CE} = 2 \text{ V})$	V _{BE(on)}	-	-	0.9	V
DYNAMIC CHARACTERISTICS					
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	C _{obo}	-	10	-	pF
Cutoff Frequency (I _C = 50 mA, V _{CE} = 2.0 V, f = 100 MHz)	f _T	_	180	-	MHz
SWITCHING TIMES					
Delay Time (V _{CC} = 10 V, I _C = 0.5 A, I _{B1} = 25 mA, I _{B2} = -25 mA)	t _d	-	13	-	ns
Rise Time (V _{CC} = 10 V, I _C = 0.5 A, I _{B1} = 25 mA, I _{B2} = -25 mA)	t _r	_	18	-	ns
Storage Time (V _{CC} = 10 V, I _C = 0.5 A, I _{B1} = 25 mA, I _{B2} = -25 mA)	t _s	-	700	-	ns
Fall Time (V _{CC} = 10 V, I _C = 0.5 A, I _{B1} = 25 mA, I _{B2} = -25 mA)	t _f	-	80	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Condition: Pulse Width = 300 μ sec, Duty Cycle $\leq 2\%$

TYPICAL CHARACTERISTICS



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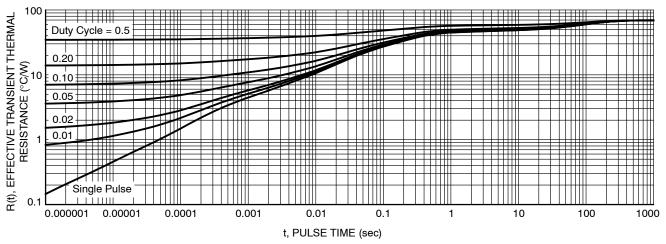
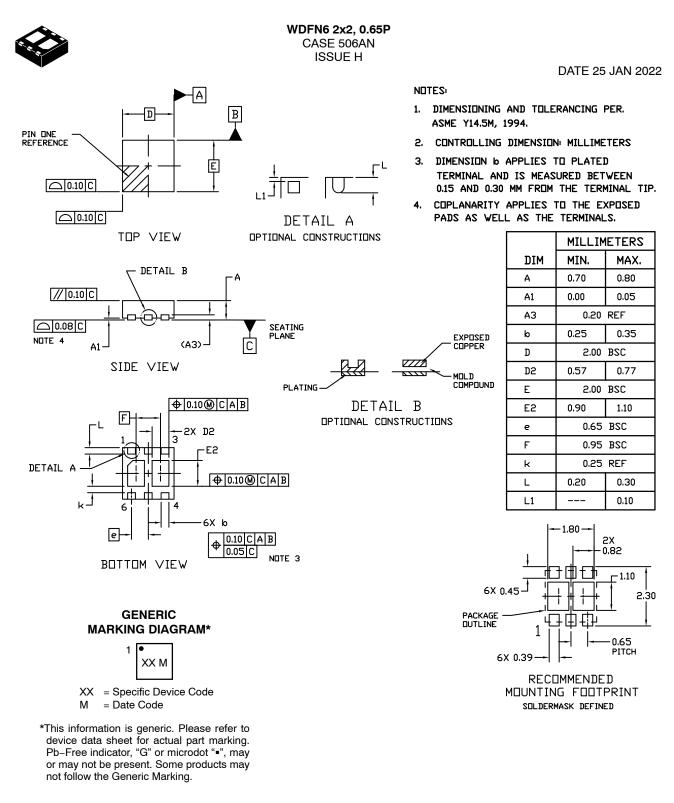


Figure 13. Thermal Resistance by Transistor

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DESCRIPTION:	WDFN6 2x2, 0.65P		PAGE 1 OF 1	

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